

# TPS82084 (2-A)/TPS82085 (3-A) 高效降压转换器 MicroSiP™ 模块

## 1 特性

- 薄型 MicroSiP™ 电源模块
- DCS-Control 拓扑
- 效率高达 95%
- 17 $\mu$ A 工作静态电流
- -40°C 至 125°C 工作温度范围
- 断续短路保护
- 2.5V 至 6V 输入电压范围
- 可调输出电压: 0.8V 至  $V_{IN}$
- 可实现轻负载效率的省电模式
- 可实现最低压降的 100% 占空比
- 输出放电功能
- 电源正常状态输出
- 集成软启动, 并支持预偏置启动
- 过热保护
- 符合 CISPR11 B 级要求
- 2.8mm x 3.0mm x 1.3mm 8 引脚  $\mu$ SiL 封装

## 2 应用

- 光学模块
- 单板计算机
- 固态硬盘
- 地铁数据中心
- 音频/视频控制系统
- 雷达

## 3 说明

TPS82084/5 是经优化的 2A/3A 降压转换器 MicroSiP™ 模块, 兼具小型解决方案尺寸和高效率优势。该电源模块集成有同步降压转换器和电感, 可简化设计、减少外部元件并节省印刷电路板 (PCB) 面积。该器件采用紧凑的薄型封装, 适合通过标准表面贴装设备进行自动组装。

为了最大限度地提高效率, 该转换器以 2.4MHz 的标称开关频率工作在脉宽调制 (PWM) 模式下, 并且会在轻负载电流时自动进入节能工作模式。在节能模式下, 器件的工作静态电流典型值为 17 $\mu$ A。凭借 DCS-Control 拓扑, 该器件可实现出色的负载瞬态性能和精确的输出稳压。器件的 EN 和 PG 引脚支持顺序配置, 可带来灵活的系统设计。集成的软启动功能降低了输入电源需要提供的浪涌电流。过温保护和自动切断短路保护功能使得该解决方案稳健而可靠。

器件信息 (1)

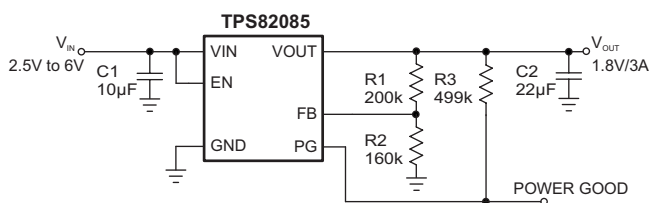
| 器件型号     | 封装            | 封装尺寸 (标称值)    |
|----------|---------------|---------------|
| TPS82085 | $\mu$ SiL (8) | 2.8mm x 3.0mm |
| TPS82084 | $\mu$ SiL (8) | 2.8mm x 3.0mm |

器件比较

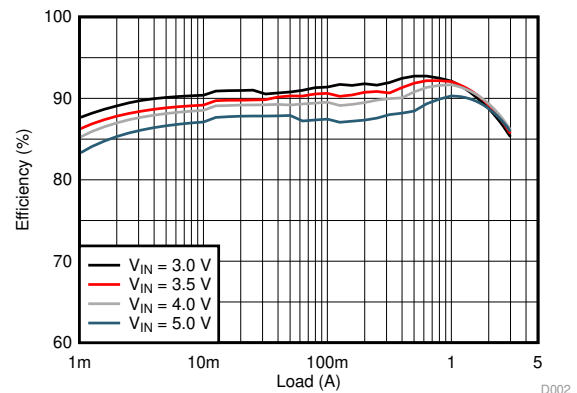
| 器件型号     | 输出电流 |
|----------|------|
| TPS82084 | 2A   |
| TPS82085 | 3A   |

(1) 如需了解所有可用封装, 请参阅数据表末尾的可订购产品附录。

1.8V 输出应用



1.8V 输出效率



D002



## 目录

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## 4 修订历史记录

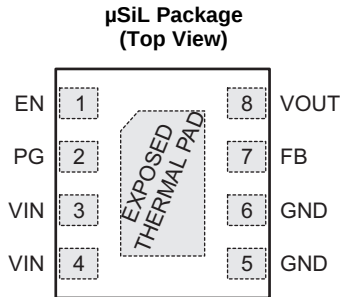
| Changes from Revision C (September 2018) to Revision D                                                         | Page |
|----------------------------------------------------------------------------------------------------------------|------|
| • 更正了标题中的器件编号                                                                                                  | 1    |
| • Add the input voltage range for the output voltage discharge feature in <a href="#">Enable and Disable</a> . | 9    |

| Changes from Revision B (April 2015) to Revision C                                                   | Page |
|------------------------------------------------------------------------------------------------------|------|
| • 已添加 在此数据表中添加 TPS82084 器件                                                                           | 1    |
| • Changed from –40 °C to –55 °C for storage temperature range                                        | 3    |
| • Added thermal information for TPS82085EVM-672. Updated thermal metric value.                       | 4    |
| • 已添加 power save mode waveform diagram to <a href="#">Power Save Mode (PSM)</a>                      | 8    |
| • 已添加 typical value of the EN pin high/low level input voltage in <a href="#">Enable and Disable</a> | 9    |
| • 已添加 pg pin logic table in <a href="#">Power Good Output</a>                                        | 9    |
| • 已添加 integrated inductor information in <a href="#">Application Information</a>                     | 10   |
| • 已添加 additional efficiency curves and a reference hyperlink to the BOM, <a href="#">表 3</a>         | 12   |
| • 已添加 radiated emission performance graph                                                            | 14   |

| Changes from Revision A (April 2015) to Revision B                                            | Page |
|-----------------------------------------------------------------------------------------------|------|
| • Changed the <a href="#">ESD Ratings</a> Charged device model (CDM) From: ±500 V To: ±1000 V | 3    |

| Changes from Original (October 2014) to Revision A | Page |
|----------------------------------------------------|------|
| • 已将数据手册从 3 页产品预览更改为量产数据                           | 1    |

## 5 Pin Configuration and Functions



**Pin Functions**

| PIN                 |     | I/O | DESCRIPTION                                                                                                                                                              |
|---------------------|-----|-----|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME                | NO. |     |                                                                                                                                                                          |
| EN                  | 1   | I   | Enable pin. Pull High to enable the device. Pull Low to disable the device. This pin has an internal pull-down resistor of typically 400 kΩ when the device is disabled. |
| PG                  | 2   | O   | Power good open drain output pin. A pull-up resistor can be connected to any voltage less than 6V. Leave it open if it is not used.                                      |
| VIN                 | 3,4 | PWR | Input voltage pin.                                                                                                                                                       |
| GND                 | 5,6 |     | Ground pin.                                                                                                                                                              |
| FB                  | 7   | I   | Feedback reference pin. An external resistor divider connected to this pin programs the output voltage.                                                                  |
| VOUT                | 8   | PWR | Output voltage pin.                                                                                                                                                      |
| Exposed Thermal Pad |     |     | The exposed thermal pad must be connected to the GND pin. Must be soldered to achieve appropriate power dissipation and mechanical reliability.                          |

## 6 Specifications

### 6.1 Absolute Maximum Ratings<sup>(1)</sup>

|                                    |                       | MIN  | MAX | UNIT |
|------------------------------------|-----------------------|------|-----|------|
| Voltage at pins <sup>(2)</sup>     | EN, PG, VIN, FB, VOUT | -0.3 | 7   | V    |
| Sink current                       | PG                    |      | 1.0 | mA   |
| Module operating temperature range |                       | -40  | 125 | °C   |
| Storage temperature range          |                       | -55  | 125 | °C   |

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground pin.

### 6.2 ESD Ratings

|                    |                         |                                                                                | VALUE | UNIT |
|--------------------|-------------------------|--------------------------------------------------------------------------------|-------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 | V    |
|                    |                         | Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±1000 |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommend Operating Conditions

Over operating free-air temperature range, unless otherwise noted.

|                 |                                     | MIN | MAX | UNIT |
|-----------------|-------------------------------------|-----|-----|------|
| V <sub>IN</sub> | Input voltage range                 | 2.5 | 6   | V    |
| V <sub>PG</sub> | Power good pull-up resistor voltage |     | 6   | V    |

## Recommend Operating Conditions (continued)

Over operating free-air temperature range, unless otherwise noted.

|                  |                                                   | MIN | MAX             | UNIT |
|------------------|---------------------------------------------------|-----|-----------------|------|
| V <sub>OUT</sub> | Output voltage range                              | 0.8 | V <sub>IN</sub> | V    |
| I <sub>OUT</sub> | Output current range, TPS82084 <sup>(1)</sup>     | 0   | 2               | A    |
|                  | Output current range, TPS82085 <sup>(1)</sup>     | 0   | 3               | A    |
| T <sub>J</sub>   | Module operating temperature range <sup>(1)</sup> | -40 | 125             | °C   |

- (1) The module operating temperature range includes module self temperature rise and IC junction temperature rise. In applications where high power dissipation is present, the maximum operating temperature or maximum output current must be derated.

## 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | TPS82084/5SIL<br>(JEDEC 51-5) | TPS82085EVM-672    | UNIT |
|-------------------------------|----------------------------------------------|-------------------------------|--------------------|------|
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 64.6                          | 46.6               | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 30.1                          | n/a <sup>(2)</sup> |      |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 23.5                          | n/a <sup>(2)</sup> |      |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 0.1                           | 0.1                |      |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 23.3                          | 24.6               |      |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | 17.2                          | 15.4               |      |

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953](#)

- (2) Not applicable to an EVM

## 6.5 Electrical Characteristics

T<sub>J</sub> = -40°C to 125°C and V<sub>IN</sub> = 2.5V to 6V. Typical values are at T<sub>J</sub> = 25°C and V<sub>IN</sub> = 3.6V, unless otherwise noted.

| PARAMETER                     |                                   | TEST CONDITIONS                                                                                   | MIN | TYP  | MAX  | UNIT |
|-------------------------------|-----------------------------------|---------------------------------------------------------------------------------------------------|-----|------|------|------|
| <b>SUPPLY</b>                 |                                   |                                                                                                   |     |      |      |      |
| V <sub>IN</sub>               | Input voltage range               |                                                                                                   | 2.5 |      | 6    | V    |
| I <sub>Q</sub>                | Quiescent current into VIN        | No load, device not switching<br>T <sub>J</sub> = -40°C to 85°C, V <sub>IN</sub> = 2.5 V to 5.5 V |     | 17   | 25   | μA   |
| I <sub>SD</sub>               | Shutdown current into VIN         | EN = Low,<br>T <sub>J</sub> = -40°C to 85°C, V <sub>IN</sub> = 2.5 V to 5.5 V                     |     | 0.7  | 5    | μA   |
| V <sub>UVLO</sub>             | Under voltage lock out threshold  | V <sub>IN</sub> falling                                                                           | 2.1 | 2.2  | 2.3  | V    |
|                               |                                   | V <sub>IN</sub> rising                                                                            | 2.3 | 2.4  | 2.5  | V    |
| T <sub>JSD</sub>              | Thermal shutdown threshold        | T <sub>J</sub> rising                                                                             |     | 150  |      | °C   |
|                               | Thermal shutdown hysteresis       | T <sub>J</sub> falling                                                                            |     | 20   |      | °C   |
| <b>LOGIC INTERFACE EN</b>     |                                   |                                                                                                   |     |      |      |      |
| V <sub>IH</sub>               | High-level input voltage          |                                                                                                   | 1.0 |      |      | V    |
| V <sub>IL</sub>               | Low-level input voltage           |                                                                                                   |     |      | 0.4  | V    |
| I <sub>IKG(EN)</sub>          | Input leakage current into EN pin | EN = High                                                                                         |     | 0.01 | 0.16 | μA   |
| R <sub>PD</sub>               | Pull-down resistance at EN pin    | EN = Low                                                                                          |     | 400  |      | kΩ   |
| <b>SOFT START, POWER GOOD</b> |                                   |                                                                                                   |     |      |      |      |
| t <sub>SS</sub>               | Soft start time                   | Time from EN high to 95% of V <sub>OUT</sub> nominal                                              |     | 0.8  |      | ms   |
| V <sub>PG</sub>               | Power good threshold              | V <sub>OUT</sub> rising, referenced to V <sub>OUT</sub> nominal                                   | 93% | 95%  | 98%  |      |
|                               |                                   | V <sub>OUT</sub> falling, referenced to V <sub>OUT</sub> nominal                                  | 88% | 90%  | 93%  |      |
| V <sub>PG,OL</sub>            | Low-level output voltage          | I <sub>sink</sub> = 1mA                                                                           |     |      | 0.4  | V    |
| I <sub>IKG(PG)</sub>          | Input leakage current into PG pin | V <sub>PG</sub> = 5V                                                                              |     | 0.01 | 0.16 | μA   |

## Electrical Characteristics (continued)

$T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  and  $V_{IN} = 2.5\text{V}$  to  $6\text{V}$ . Typical values are at  $T_J = 25^{\circ}\text{C}$  and  $V_{IN} = 3.6\text{V}$ , unless otherwise noted.

| PARAMETER           |                                    | TEST CONDITIONS                                                     | MIN | TYP  | MAX      | UNIT             |
|---------------------|------------------------------------|---------------------------------------------------------------------|-----|------|----------|------------------|
| <b>OUTPUT</b>       |                                    |                                                                     |     |      |          |                  |
| $V_{OUT}$           | Output voltage range               |                                                                     | 0.8 |      | $V_{IN}$ | V                |
| $V_{FB}$            | Feedback regulation voltage        | PWM mode                                                            | 792 | 800  | 808      | mV               |
|                     |                                    | PSM mode, $C_{OUT} = 22\ \mu\text{F}$                               | 792 | 800  | 817      |                  |
| $I_{lkg(FB)}$       | Feedback input leakage current     | $V_{FB} = 0.8\ \text{V}$                                            |     | 0.01 | 0.1      | $\mu\text{A}$    |
| $R_{DIS}$           | Output discharge resistor          | EN = Low, $V_{OUT} = 1.8\ \text{V}$                                 |     | 260  |          | $\Omega$         |
|                     | Line regulation                    | $I_{OUT} = 1\ \text{A}$ , $V_{IN} = 2.5\ \text{V}$ to $6\ \text{V}$ |     | 0.02 |          | %/V              |
|                     | Load regulation                    | $I_{OUT} = 0.5\ \text{A}$ to $3\ \text{A}$                          |     | 0.16 |          | %/A              |
| <b>POWER SWITCH</b> |                                    |                                                                     |     |      |          |                  |
| $R_{DS(on)}$        | High-side FET on-resistance        | $I_{SW} = 500\ \text{mA}$                                           |     | 31   | 56       | $\text{m}\Omega$ |
|                     | Low-side FET on-resistance         | $I_{SW} = 500\ \text{mA}$                                           |     | 23   | 45       | $\text{m}\Omega$ |
| $R_{DP}$            | Dropout resistance                 | 100% mode                                                           |     | 69   |          | $\text{m}\Omega$ |
| $I_{LIMF}$          | High-side FET switch current limit | TPS82085                                                            | 3.7 | 4.6  | 5.5      | A                |
|                     |                                    | TPS82084                                                            |     | 3.6  |          |                  |
| $f_{SW}$            | PWM switching frequency            | $I_{OUT} = 1\ \text{A}$                                             |     | 2.4  |          | MHz              |

## 6.6 Typical Characteristics

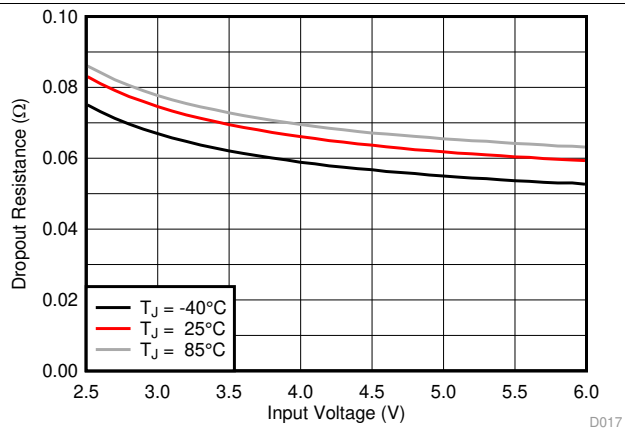


图 1. Dropout Resistance

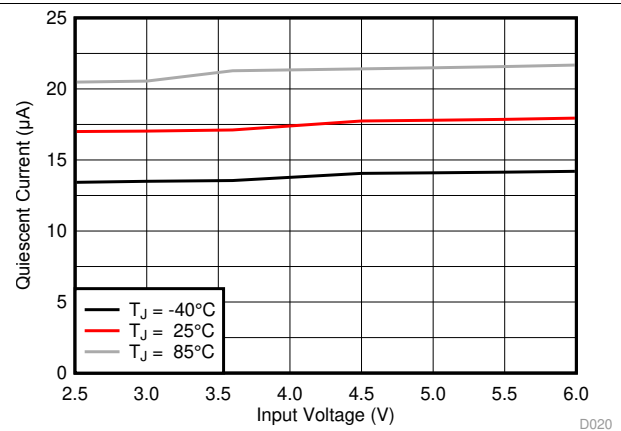


图 2. Quiescent Current

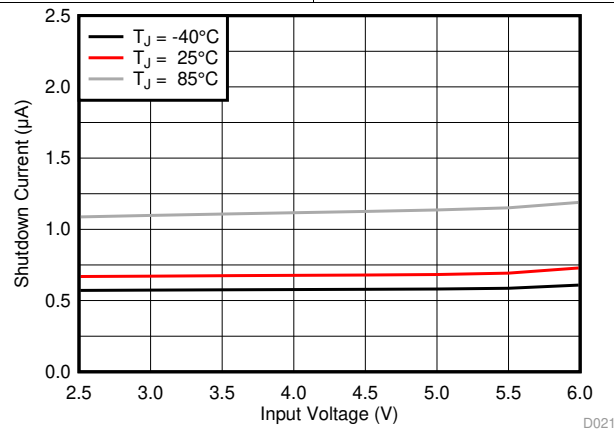


图 3. Shutdown Current

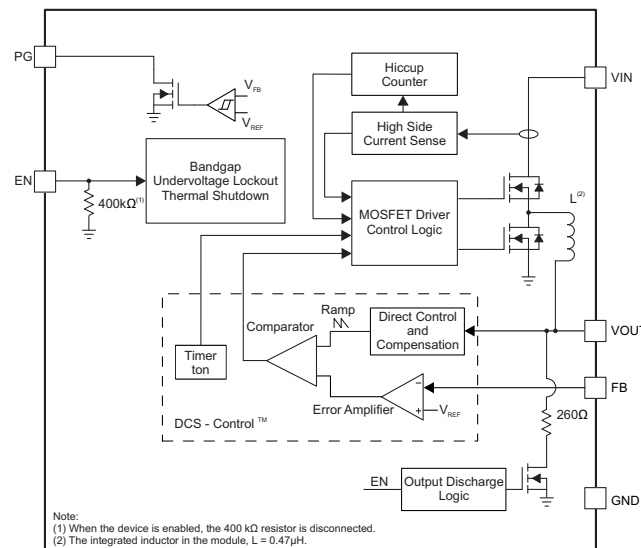
## 7 Detailed Description

### 7.1 Overview

The TPS82084/5 synchronous step-down converter power modules are based on DCS-Control™ (Direct Control with Seamless transition into Power Save Mode). This is an advanced regulation topology that combines the advantages of hysteretic, voltage and current mode control.

The DCS-Control™ topology operates in PWM (Pulse Width Modulation) mode for medium to heavy load conditions and in PSM (Power Save Mode) at light load currents. In PWM, the converter operates with its nominal switching frequency of 2.4 MHz having a controlled frequency variation over the input voltage range. As the load current decreases, the converter enters Power Save Mode, reducing the switching frequency and minimizing the IC's quiescent current to achieve high efficiency over the entire load current range. DCS-Control™ supports both operation modes using a single building block and therefore has a seamless transition from PWM to PSM without effects on the output voltage. The device offers excellent DC voltage regulation and load transient regulation, combined with low output voltage ripple, minimizing interference with RF circuits.

### 7.2 Functional Block Diagram



### 7.3 Feature Description

#### 7.3.1 Power Save Mode (PSM)

The device includes a fixed on-time ( $t_{ON}$ ) circuitry. This  $t_{ON}$ , in steady-state operation in PWM and PSM modes, is estimated as:

$$t_{ON} = 420 \text{ ns} \times \frac{V_{OUT}}{V_{IN}}$$

$$f_{PSM} = \frac{2 \times I_{OUT}}{t_{ON}^2 \times \frac{V_{IN}}{V_{OUT}} \times \frac{V_{IN} - V_{OUT}}{L}} \quad (1)$$

To maintain high efficiency at light loads, the device enters Power Save Mode seamlessly when the load current decreases. This happens when the load current becomes smaller than half the inductor's ripple current. In PSM, the converter operates with a reduced switching frequency and with a minimum quiescent current to maintain high efficiency. The on time in PSM is also based on the same  $t_{ON}$  circuitry. The switching frequency in PSM is shown in 公式 1.

## Feature Description (接下页)

In PSM, the output voltage rises slightly above the nominal output voltage in PWM mode. This effect is reduced by increasing the output capacitance. The output voltage accuracy in PSM operation is reflected in the electrical specification table and given for a 22-μF output capacitor.

During PAUSE period in PSM (shown in 图 4), the device does not change the PG pin state nor does it detect an UVLO event, in order to achieve a minimum quiescent current and maintain high efficiency at light loads.

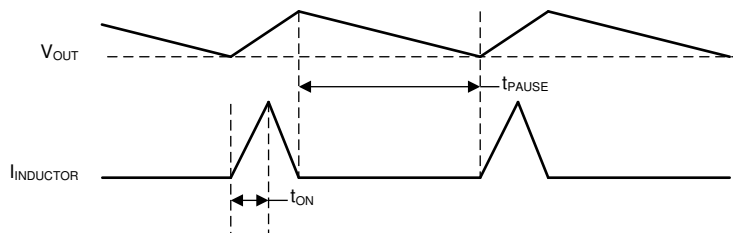


图 4. Power Save Mode Waveform Diagram

### 7.3.2 Low Dropout Operation (100% Duty Cycle)

The device offers a low input to output voltage differential by entering 100% duty cycle mode. In this mode, the high-side MOSFET switch is constantly turned on. This is particularly useful in battery powered applications to achieve longest operation time by taking full advantage of the whole battery voltage range. The minimum input voltage to maintain a minimum output voltage is given by:

$$V_{IN(min)} = V_{OUT(min)} + I_{OUT} \times R_{DP} \quad (2)$$

Where

$R_{DP}$  = Resistance from  $V_{IN}$  to  $V_{OUT}$ , including high-side FET on-resistance and DC resistance of the inductor.

$V_{OUT(min)}$  = Minimum output voltage the load can accept.

### 7.3.3 Soft Startup

The device has an internal soft start circuit which ramps up the output voltage to the nominal voltage during a soft start time of typically 0.8ms. This avoids excessive inrush current and creates a smooth output voltage slope. It also prevents excessive voltage drops of primary cells and rechargeable batteries with high internal impedance. The device is able to monotonically start into a pre-biased output capacitor. The device starts with the applied bias voltage and ramps the output voltage to its nominal value.

### 7.3.4 Switch Current Limit and Short Circuit Protection (Hiccup-Mode)

The switch current limit prevents the device from high inductor current and from drawing excessive current from the battery or input voltage rail. Excessive current might occur with a heavy load/shorted output circuit condition. If the inductor peak current reaches the switch current limit, the high-side FET is turned off and the low-side FET is turned on to ramp down the inductor current. Once this switch current limit is triggered 32 times, the device stops switching and enables the output discharge. The device then automatically start a new startup after a typical delay time of 66μs has passed. This is named HICCUP short circuit protection. The devices repeat this mode until the high load condition disappears.

### 7.3.5 Undervoltage Lockout

To avoid mis-operation of the device at low input voltages, an under voltage lockout is implemented, which shuts down the devices at voltages lower than  $V_{UVLO}$  with a hysteresis of 200 mV.

### 7.3.6 Thermal Shutdown

The device goes into thermal shutdown and stops switching once the junction temperature exceeds  $T_{JSD}$ . Once the device temperature falls below the threshold by 20°C, the device returns to normal operation automatically.

## 7.4 Device Functional Modes

### 7.4.1 Enable and Disable

The device is enabled by setting the EN pin to a logic High (typical 0.8 V). Accordingly, shutdown mode is forced if the EN pin is pulled Low (typical 0.7 V) with a shutdown current of typically 0.7  $\mu$ A. An internal resistor of 260  $\Omega$  discharges the output via the VOUT pin smoothly when the device is disabled. The output discharge function also works when thermal shutdown, undervoltage lockout or short circuit protection are triggered. The output discharge function stops working when the input voltage has decreased to around 0.5V.

An internal pull-down resistor of 400 k $\Omega$  is connected to the EN pin when the EN pin is Low. The pull-down resistor is disconnected when the EN pin is High.

### 7.4.2 Power Good Output

The device has a power good (PG) output. The PG pin goes high impedance once the output is above 95% of the nominal voltage, and is driven low once the output voltage falls below typically 90% of the nominal voltage. The PG pin is an open drain output and is specified to sink up to 1 mA. The power good output requires a pull-up resistor connecting to any voltage rail less than 6 V.

The PG signal can be used for sequencing of multiple rails by connecting it to the EN pin of other converters. Leave the PG pin floating when it is not used. 表 1 shows the PG pin logic.

**表 1. PG Pin Logic**

|                      | DEVICE CONDITIONS                  | LOGIC STATUS |     |
|----------------------|------------------------------------|--------------|-----|
|                      |                                    | HIGH Z       | LOW |
| Enable               | EN = High, $V_{FB} \geq V_{PG}$    | √            |     |
|                      | EN = High, $V_{FB} < V_{PG}$       |              | √   |
| Shutdown             | EN = Low                           |              | √   |
| Thermal Shutdown     | $T_J > T_{JSD}$                    |              | √   |
| UVLO                 | $0.5\text{ V} < V_{IN} < V_{UVLO}$ |              | √   |
| Power Supply Removal | $V_{IN} \leq 0.5\text{ V}$         | √            |     |

## 8 Application and Implementation

### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The TPS82084/5 are synchronous step-down converter power modules whose output voltage is adjusted by component selection. The following section discusses the design of the external components to complete the power supply design for several input and output voltage options by using typical applications as a reference.

The required power inductor is integrated inside the TPS82084/5. The inductor is shielded and has an inductance of 0.47  $\mu\text{H}$  with approximately a  $\pm 20\%$  tolerance. The TPS82084 and TPS82085 are pin-to-pin and BOM-to-BOM compatible, differing only in their rated output current.

### 8.2 Typical Applications

#### 8.2.1 1.2-V Output Application

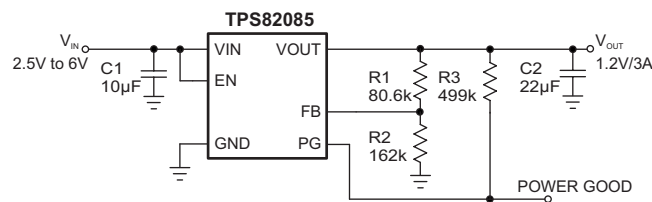


图 5. 1.2-V Output Application

##### 8.2.1.1 Design Requirements

For this design example, use the input parameters shown in 表 2.

表 2. Design Parameters

| DESIGN PARAMETER      | EXAMPLE VALUE |
|-----------------------|---------------|
| Input voltage range   | 2.5 V to 6 V  |
| Output voltage        | 1.2 V         |
| Output ripple voltage | < 20 mV       |
| Output current rating | 3 A           |

表 3 lists the components used for the example.

表 3. List of Components

| REFERENCE | DESCRIPTION                                                                                                                                                         | MANUFACTURER         |
|-----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|
| C1        | 10 $\mu\text{F}$ , Ceramic Capacitor, 10V, X7R, size 0805, GRM21BR71A106KE51                                                                                        | Murata               |
| C2        | 22 $\mu\text{F}$ , Ceramic Capacitor, 6.3V, X7R, size 0805, CL21B226MQNNNE<br>or<br>22 $\mu\text{F}$ , Ceramic Capacitor, 6.3V, X7S, size 0805, C2012X7S1A226M125AC | Samsung<br>or<br>TDK |
| R1        | Depending on the output voltage, 1% accuracy                                                                                                                        | Std                  |
| R2        | 162k $\Omega$ , 1% accuracy                                                                                                                                         | Std                  |
| R3        | 499k $\Omega$ , 1% accuracy                                                                                                                                         | Std                  |

### 8.2.1.2 Detailed Design Procedure

#### 8.2.1.2.1 Setting the Output Voltage

The output voltage is set by an external resistor divider according to the following equations:

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R1}{R2}\right) = 0.8 \text{ V} \times \left(1 + \frac{R1}{R2}\right) \quad (3)$$

R2 should not be higher than 180 kΩ to achieve high efficiency at light load while providing acceptable noise sensitivity. Larger currents through R2 improve noise sensitivity and output voltage accuracy. [图 5](#) shows a recommended external resistor divider value for a 1.2-V output. Choose appropriate resistor values for other output voltages.

#### 8.2.1.2.2 Input and Output Capacitor Selection

For best output and input voltage filtering, ceramic capacitors are required. The input capacitor minimizes input voltage ripple, suppresses input voltage spikes and provides a stable system rail for the device. A 10-μF or larger input capacitor is required. The output capacitor value can range from 22 μF up to more than 150 μF. The recommended typical output capacitor value is 22μF. Values over 150 μF may be possible with a reduced load during startup in order to avoid triggering the Hiccup short circuit protection. A feed forward capacitor is not required for proper operation.

Ceramic capacitor has a DC-Bias effect, which has a strong influence on the final effective capacitance. Choose the right capacitor carefully in combination with considering its package size and voltage rating. Ensure that the input effective capacitance is at least 5μF and the output effective capacitance is at least 8μF.

### 8.2.1.3 Application Performance Curves

$T_A = 25^\circ\text{C}$ ,  $V_{IN} = 5\text{ V}$ ,  $V_{OUT} = 1.2\text{ V}$ , BOM = 表 3 unless otherwise noted.

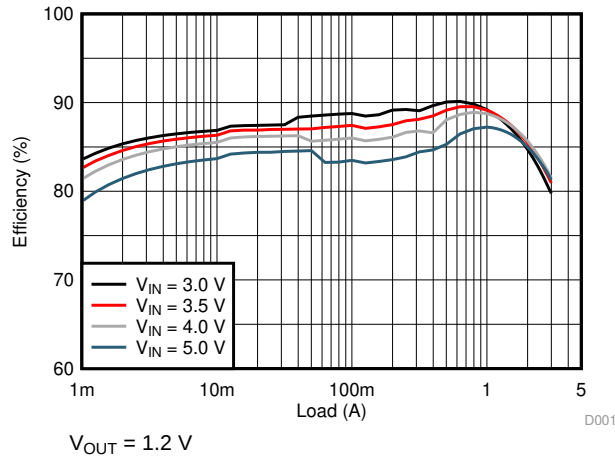


图 6. Efficiency

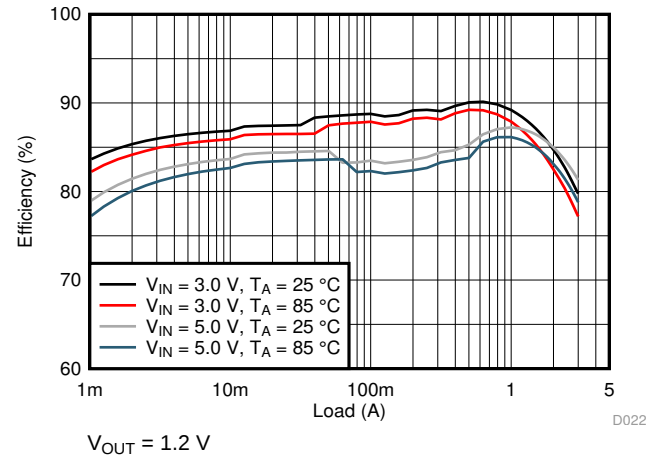


图 7. Efficiency

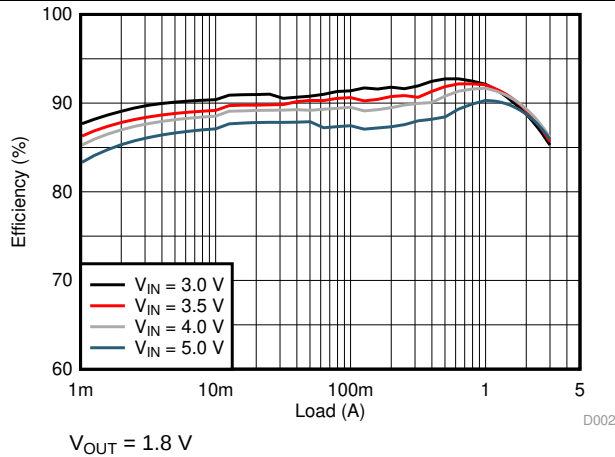


图 8. Efficiency

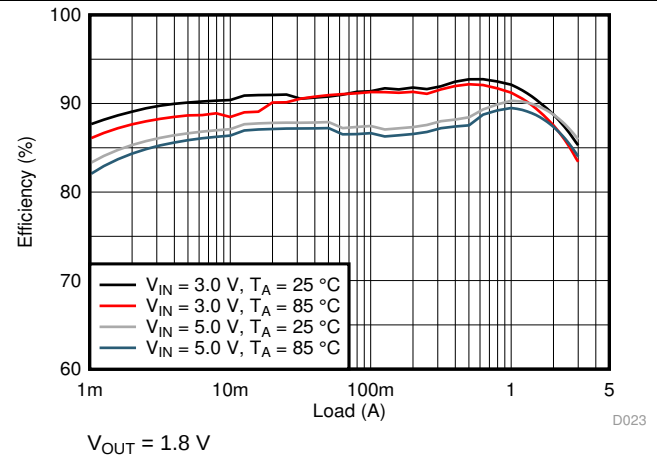


图 9. Efficiency

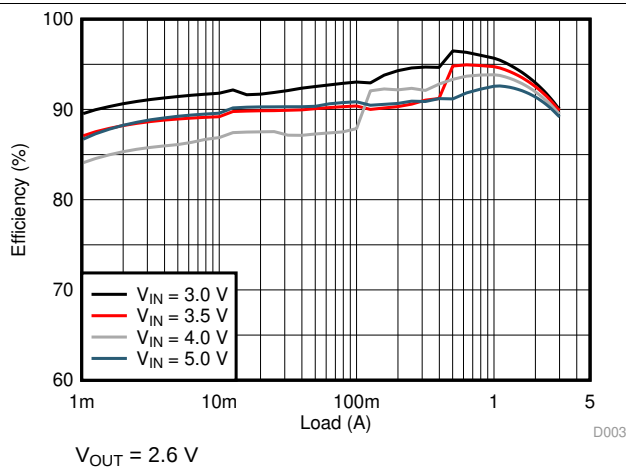


图 10. Efficiency

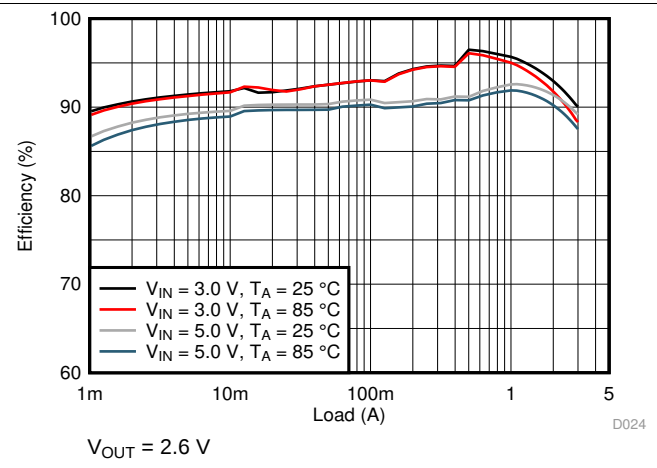


图 11. Efficiency

$T_A = 25^\circ\text{C}$ ,  $V_{IN} = 5\text{ V}$ ,  $V_{OUT} = 1.2\text{ V}$ , BOM = 表 3 unless otherwise noted.

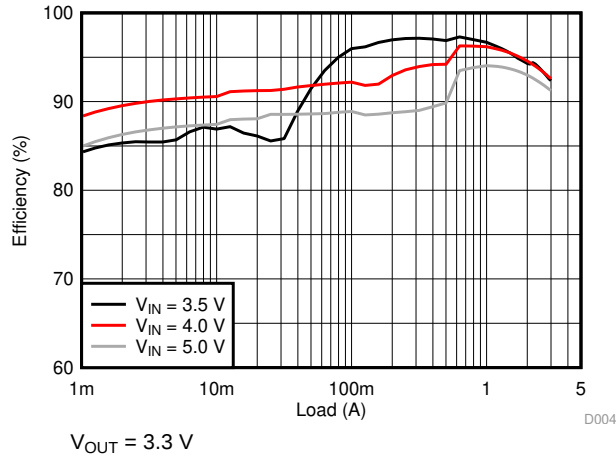


图 12. Efficiency

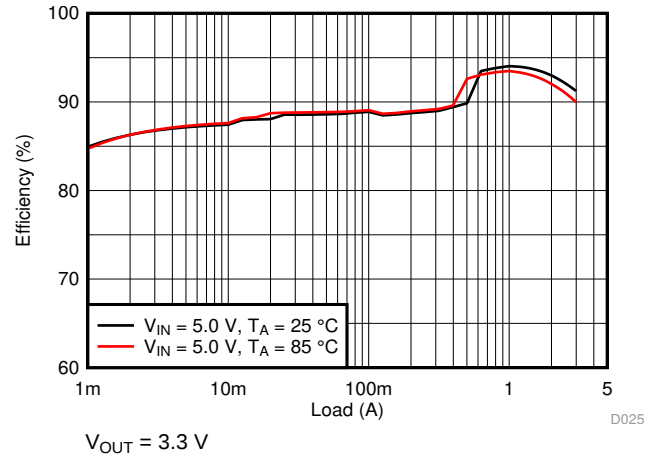


图 13. Efficiency

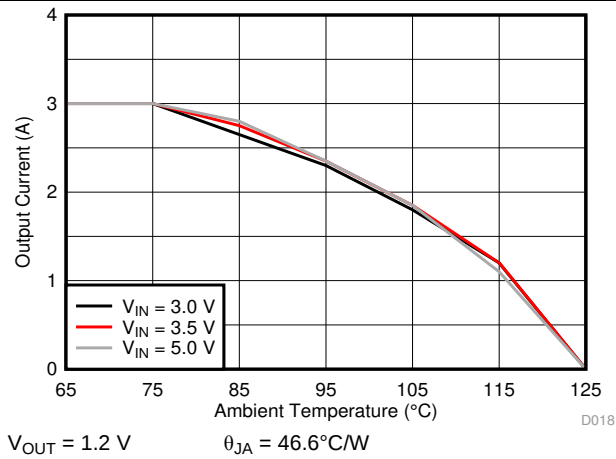


图 14. Thermal Derating

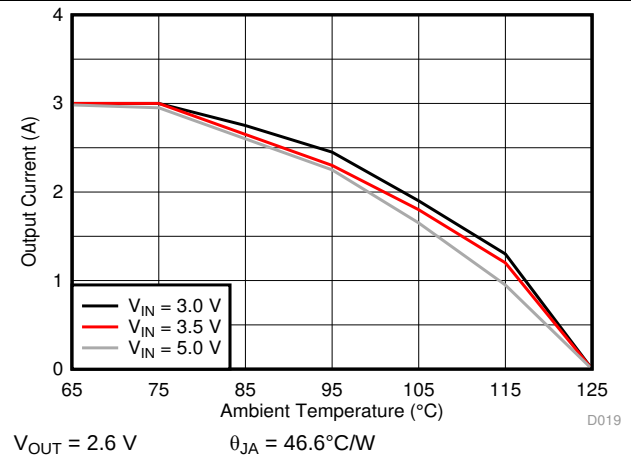


图 15. Thermal Derating

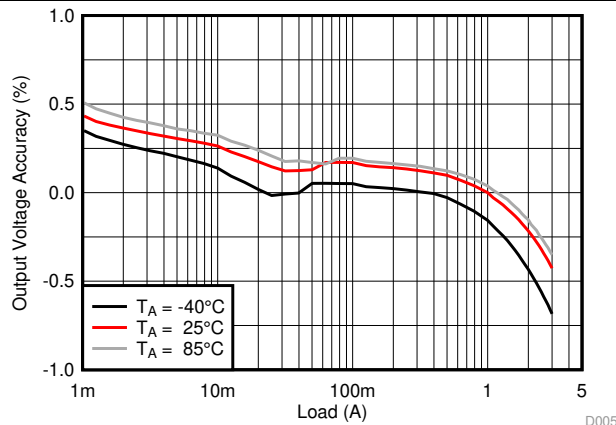


图 16. Load Regulation

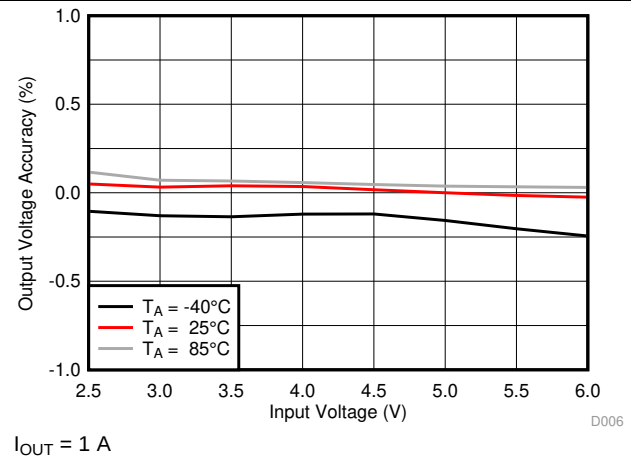
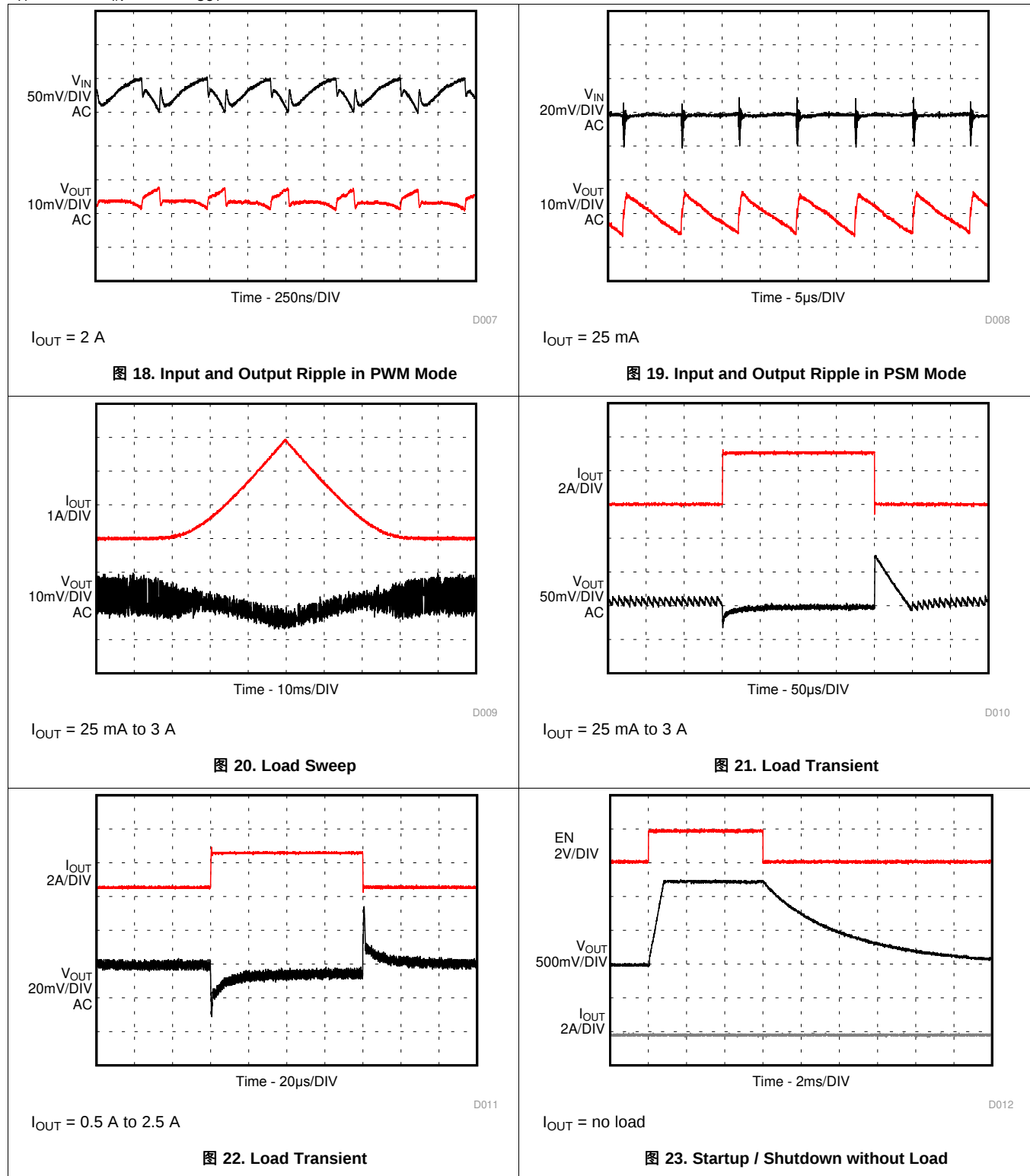


图 17. Line Regulation

$T_A = 25^\circ\text{C}$ ,  $V_{IN} = 5\text{ V}$ ,  $V_{OUT} = 1.2\text{ V}$ , BOM = 表 3 unless otherwise noted.



$T_A = 25^\circ\text{C}$ ,  $V_{IN} = 5\text{ V}$ ,  $V_{OUT} = 1.2\text{ V}$ , BOM = 表 3 unless otherwise noted.

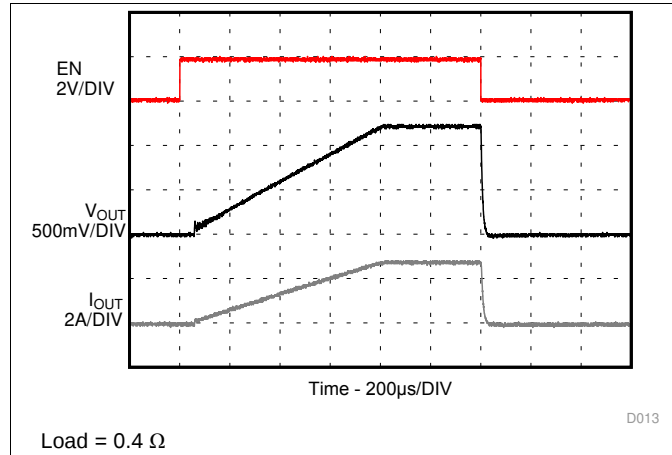


图 24. Startup / Shutdown with Resistive Load

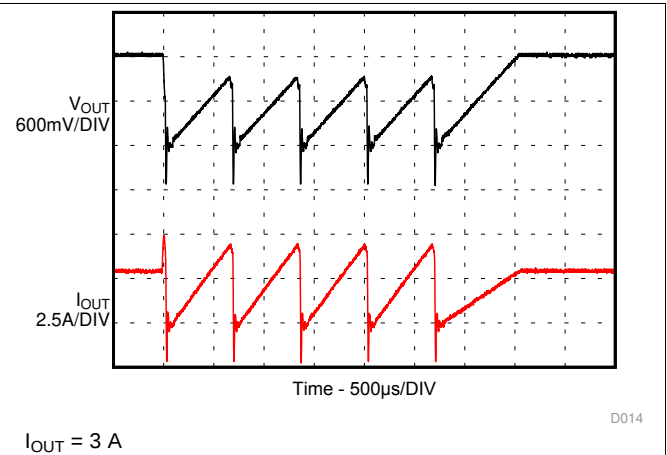


图 25. Short Circuit, HICCUP Protection Entry / Exit

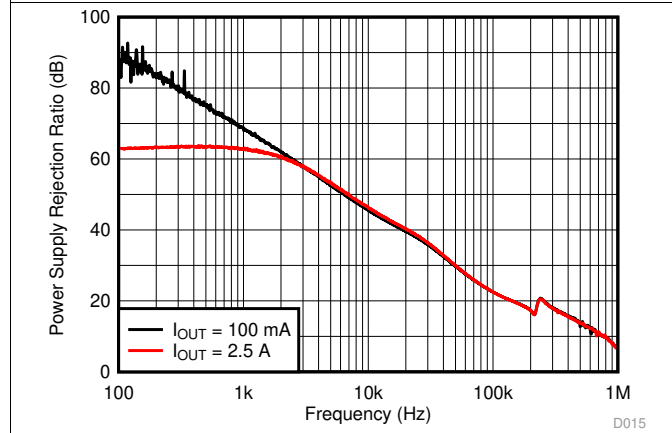


图 26. Power Supply Rejection Ratio (PSRR)

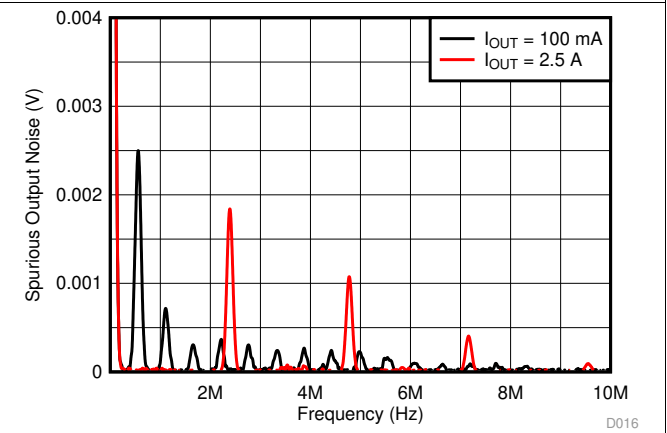


图 27. Spurious Output Noise

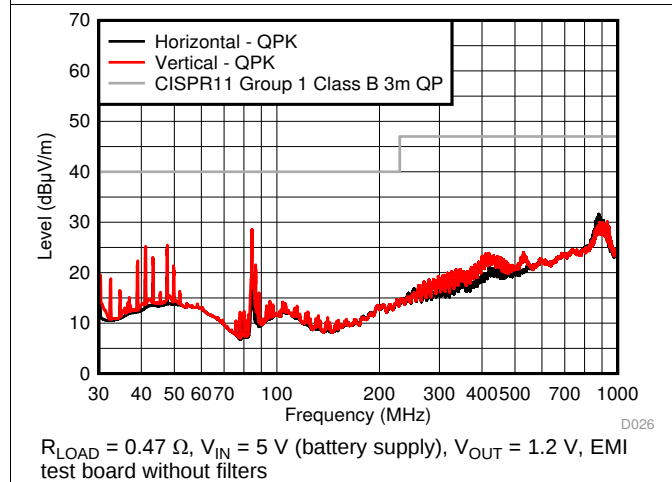


图 28. TPS82085 Radiated Emission

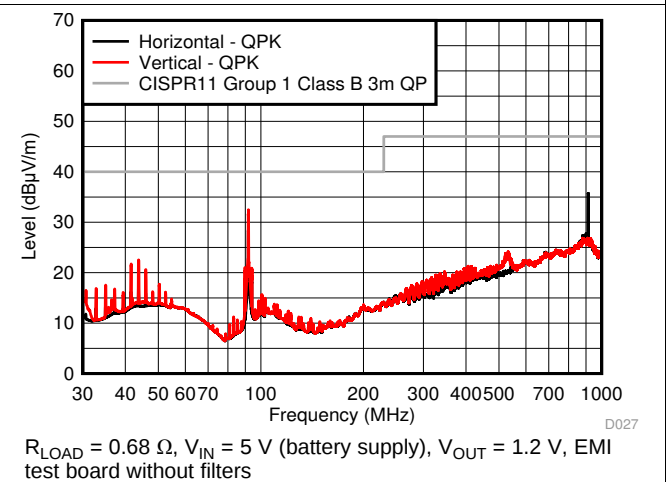


图 29. TPS82084 Radiated Emission

## 9 Power Supply Recommendations

The devices are designed to operate from an input supply voltage range between 2.5 V and 6 V. The average input current of the TPS82084/5 is calculated as:

$$I_{IN} = \frac{1}{\eta} \times \frac{V_{OUT} \times I_{OUT}}{V_{IN}} \quad (4)$$

Ensure that the power supply has a sufficient current rating for the application.

## 10 Layout

### 10.1 Layout Guidelines

- It is recommended to place all components as close as possible to the IC. Specially, the input capacitor placement must be closest to the VIN and GND pins of the device.
- Use wide and short traces for the main current paths to reduce the parasitic inductance and resistance.
- To enhance heat dissipation of the device, the exposed thermal pad should be connected to bottom or internal layer ground planes using vias.
- Refer to [Figure 30](#) for an example of component placement, routing and thermal design.
- The recommended land pattern for the TPS82084/5 is shown at the end of this data sheet. For best manufacturing results, it is important to create the pads as solder mask defined (SMD). This keeps each pad the same size and avoids solder pulling the device during reflow.

### 10.2 Layout Example

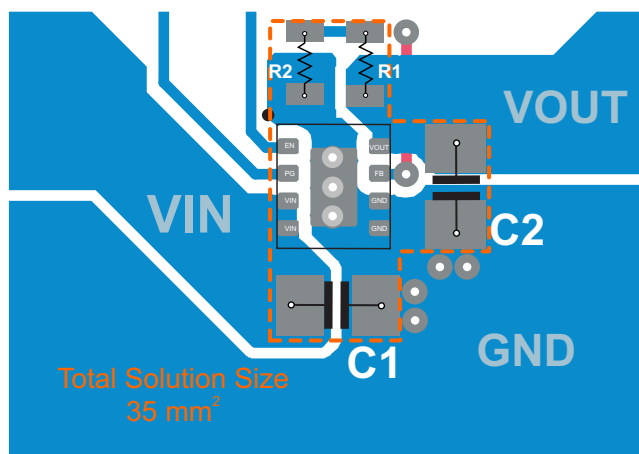


图 30. TPS82084/5 PCB Layout

### 10.3 Thermal Consideration

The TPS82084/5's output current needs to be derated when the device operates in a high ambient temperature or deliver high output power. The amount of current derated is dependent upon the input voltage, output power, PCB layout design and environmental thermal condition.

The TPS82084/5 module temperature must be kept less than the maximum rating of 125°C. Three basic approaches for enhancing thermal performance are listed below:

- Improve the power dissipation capability of the PCB design.
- Improve the thermal coupling of the component to the PCB.
- Introduce airflow into the system.

To estimate approximate module temperature of TPS82084/5, apply the typical efficiency stated in this datasheet to the desired application condition for the module power dissipation, then calculate the module temperature rise by multiplying the power dissipation by its thermal resistance. For more details on how to use the thermal parameters in real applications, see the application notes: [SZZA017](#) and [SPRA953](#).

## 11 器件和文档支持

### 11.1 器件支持

#### 11.1.1 第三方产品免责声明

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### 11.2 相关链接

下表列出了快速访问链接。类别包括技术文档、支持和社区资源、工具和软件，以及立即订购快速访问。

表 4. 相关链接

| 器件       | 产品文件夹                 | 立即订购                  | 技术文档                  | 工具与软件                 | 支持和社区                 |
|----------|-----------------------|-----------------------|-----------------------|-----------------------|-----------------------|
| TPS82085 | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> |
| TPS82084 | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> |

### 11.3 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 11.4 商标

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### 11.5 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

### 11.6 Glossary

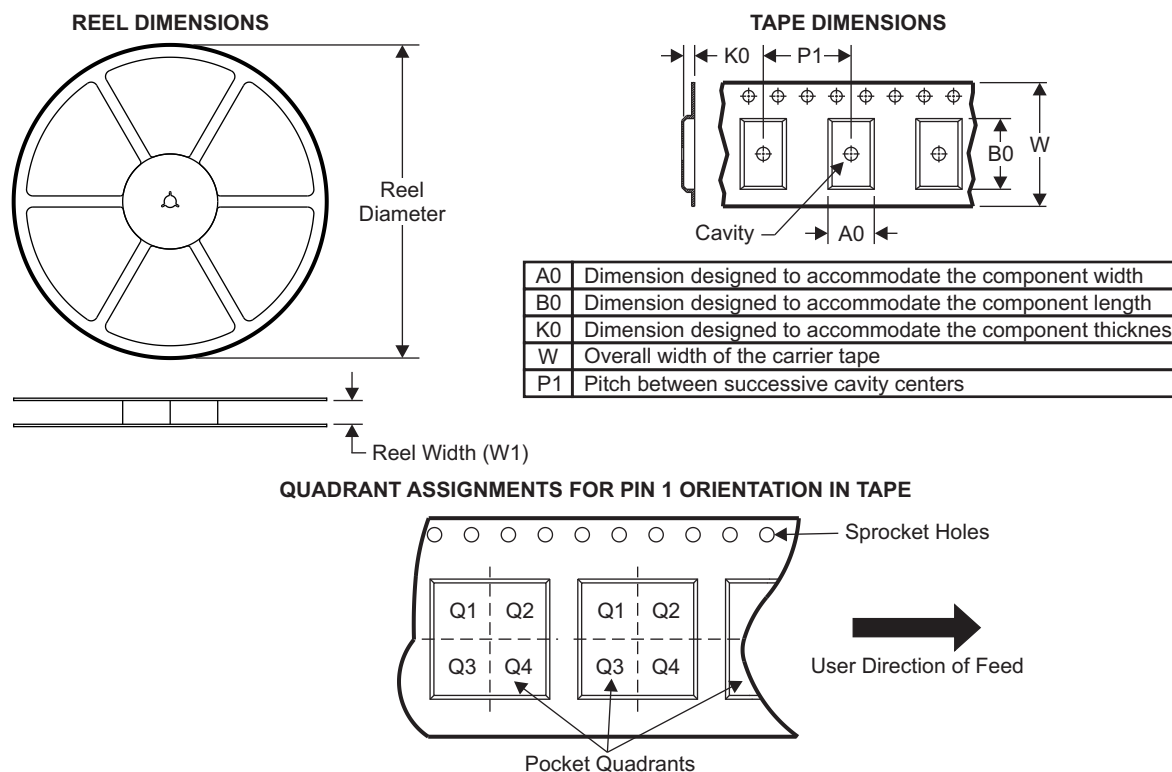
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 机械、封装和可订购信息

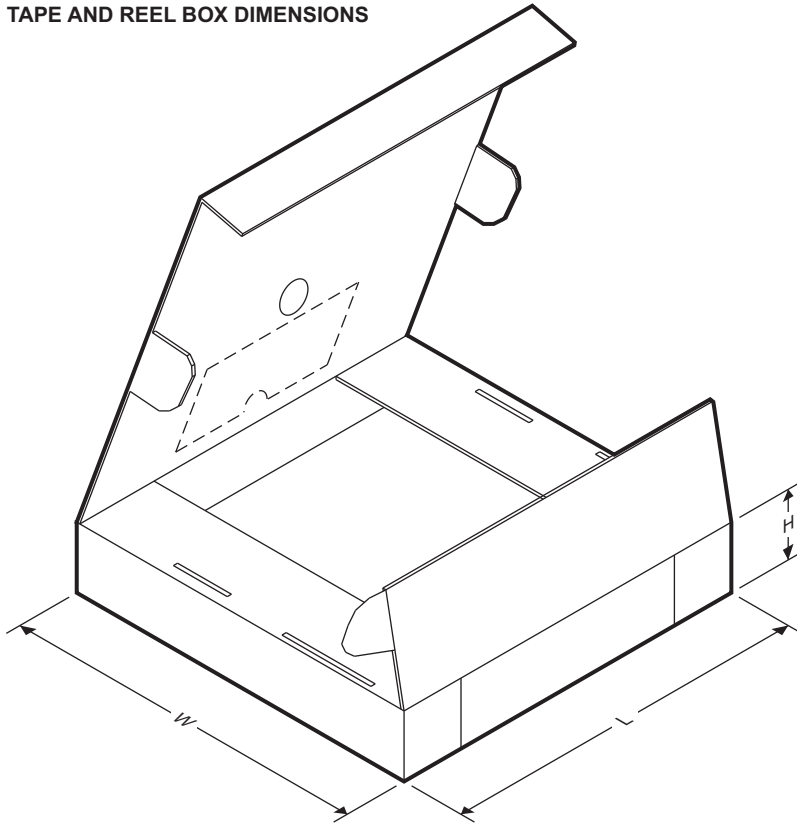
以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

## 12.1 Tape and Reel Information

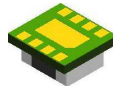


| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS82084SILR | uSiP         | SIL             | 8    | 3000 | 330.0              | 12.4               | 3.0     | 3.2     | 1.45    | 4.0     | 12.0   | Q1            |
| TPS82084SILT | uSiP         | SIL             | 8    | 250  | 178.0              | 13.2               | 3.0     | 3.2     | 1.45    | 4.0     | 12.0   | Q1            |
| TPS82085SILR | uSiP         | SIL             | 8    | 3000 | 330.0              | 12.4               | 3.0     | 3.2     | 1.45    | 4.0     | 12.0   | Q1            |
| TPS82085SILT | uSiP         | SIL             | 8    | 250  | 178.0              | 13.2               | 3.0     | 3.2     | 1.45    | 4.0     | 12.0   | Q1            |

**TAPE AND REEL BOX DIMENSIONS**



| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS82084SILR | uSiP         | SIL             | 8    | 3000 | 383         | 353        | 58          |
| TPS82084SILT | uSiP         | SIL             | 8    | 250  | 223         | 194        | 35          |
| TPS82085SILR | uSiP         | SIL             | 8    | 3000 | 383         | 353        | 58          |
| TPS82085SILT | uSiP         | SIL             | 8    | 250  | 223         | 194        | 35          |

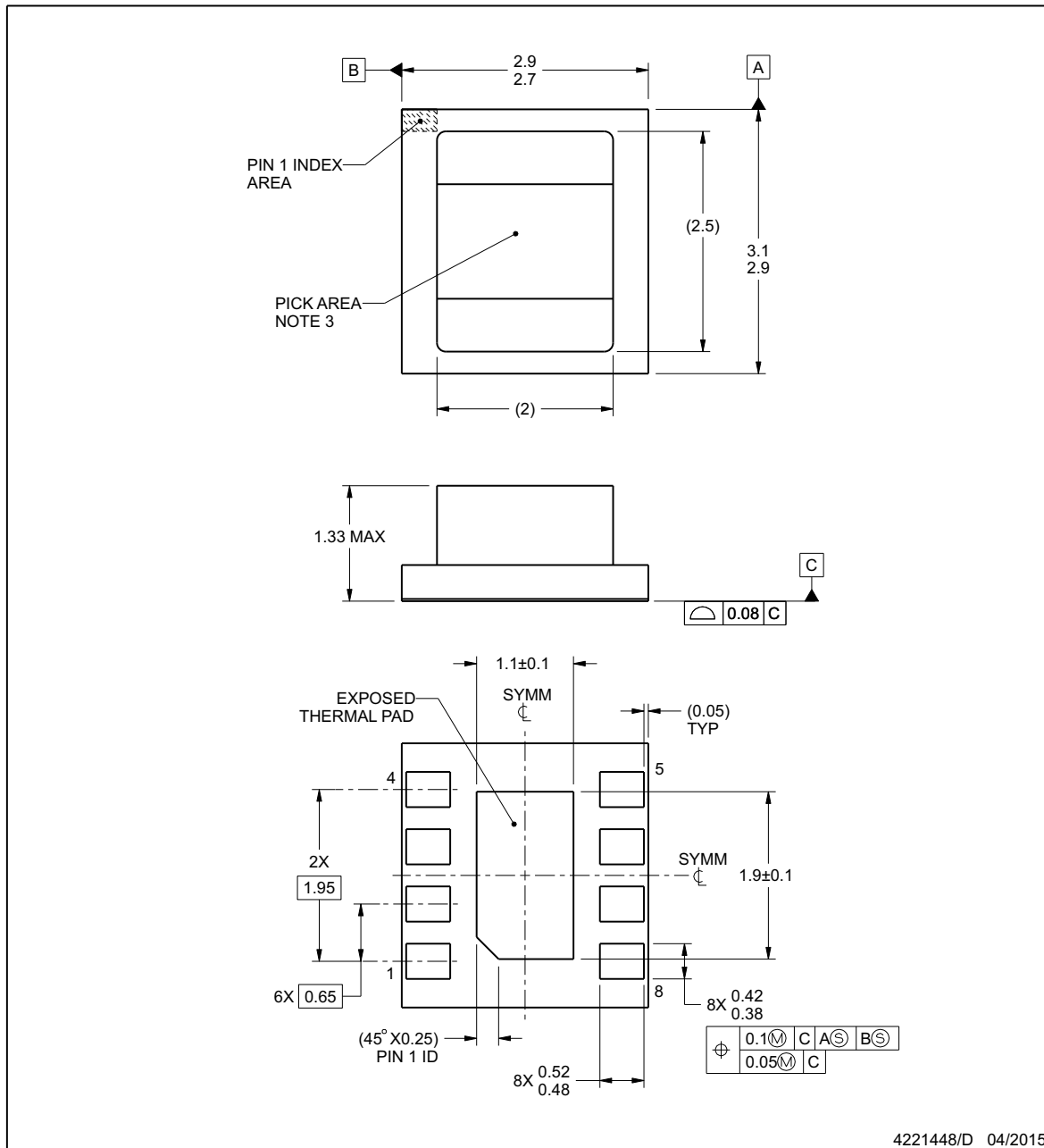


## PACKAGE OUTLINE

**SIL0008C**

**MicroSiP™ - 1.33 mm max height**

## MICRO SYSTEM IN PACKAGE



NOTES:

MicroSiP is a trademark of Texas Instruments

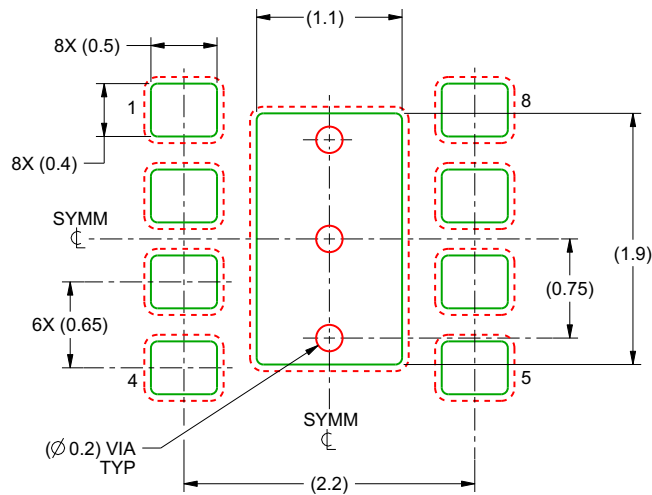
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Pick and place nozzle  $\varnothing 1.3$  mm or smaller recommended.
4. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

## EXAMPLE BOARD LAYOUT

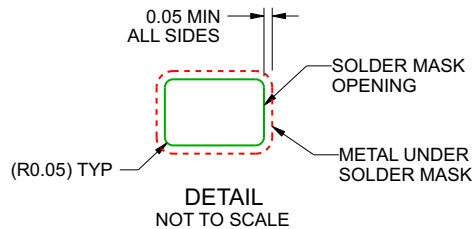
**SIL0008C**

**MicroSiP™ - 1.33 mm max height**

MICRO SYSTEM IN PACKAGE



LAND PATTERN EXAMPLE  
SOLDER MASK DEFINED  
SCALE:20X



4221448/D 04/2015

NOTES: (continued)

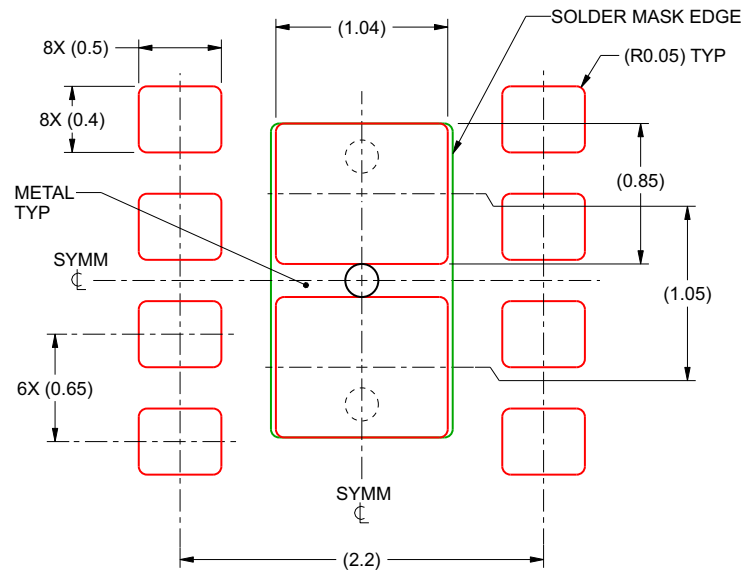
5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).

## EXAMPLE STENCIL DESIGN

**SIL0008C**

**MicroSiP™ - 1.33 mm max height**

MICRO SYSTEM IN PACKAGE



**SOLDER PASTE EXAMPLE**  
 BASED ON 0.125 mm THICK STENCIL  
 EXPOSED PAD  
 85% PRINTED SOLDER COVERAGE BY AREA  
 SCALE:25X

4221448/D 04/2015

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

## PACKAGING INFORMATION

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPS82084SILR</a> | Active        | Production           | uSiP (SIL)   8 | 3000   LARGE T&R      | Yes         | NIAU                                 | Level-2-260C-1 YEAR               | -40 to 125   | 1D                  |
| TPS82084SILR.A               | Active        | Production           | uSiP (SIL)   8 | 3000   LARGE T&R      | Yes         | NIAU                                 | Level-2-260C-1 YEAR               | -40 to 125   | 1D                  |
| <a href="#">TPS82084SILT</a> | Active        | Production           | uSiP (SIL)   8 | 250   SMALL T&R       | Yes         | Call TI                              | Level-2-260C-1 YEAR               | -40 to 125   | 1D                  |
| TPS82084SILT.A               | Active        | Production           | uSiP (SIL)   8 | 250   SMALL T&R       | Yes         | Call TI                              | Level-2-260C-1 YEAR               | -40 to 125   | 1D                  |
| <a href="#">TPS82085SILR</a> | Active        | Production           | uSiP (SIL)   8 | 3000   LARGE T&R      | Yes         | NIAU                                 | Level-2-260C-1 YEAR               | -40 to 125   | GE                  |
| TPS82085SILR.A               | Active        | Production           | uSiP (SIL)   8 | 3000   LARGE T&R      | Yes         | NIAU                                 | Level-2-260C-1 YEAR               | -40 to 125   | GE                  |
| <a href="#">TPS82085SILT</a> | Active        | Production           | uSiP (SIL)   8 | 250   SMALL T&R       | Yes         | NIAU                                 | Level-2-260C-1 YEAR               | -40 to 125   | GE                  |
| TPS82085SILT.A               | Active        | Production           | uSiP (SIL)   8 | 250   SMALL T&R       | Yes         | NIAU                                 | Level-2-260C-1 YEAR               | -40 to 125   | GE                  |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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